



晶体管光耦
Photo Transistor

AT EL1018

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

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概述 Description

EL1018 是一款由一个GaAs发光二极管和一个NPN光电晶体管组成的光电耦合器。

The EL1018 is a photoelectric coupler composed of a GaAs light-emitting diode and a NPN photo transistor.

特性 Features

- 电流转换比(CTR)范围: $\geq 80\%$ ($I_F=5\text{mA}$, $V_{CE}=5\text{V}$, $T_a=25^\circ\text{C}$)
Current transfer ratio: $\geq 80\%$ ($I_F=5\text{mA}$, $V_{CE}=5\text{V}$, $T_a=25^\circ\text{C}$)
- 输入-输出隔离电压 ($V_{ISO}=5000\text{ Vrms}$)
High isolation voltage between input and output($V_{ISO}=5000\text{ Vrms}$)
- 集电极-发射极击穿电压 $BV_{CEO}\geq 80\text{V}$
Collector - emitter breakdown voltage $BV_{CEO}\geq 80\text{V}$
- 工作温度: $-55^\circ\text{C}\sim 110^\circ\text{C}$
Operating Temperature: $-55^\circ\text{C}\sim 110^\circ\text{C}$
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022
Safety standards approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5), CQC11-471543-2022

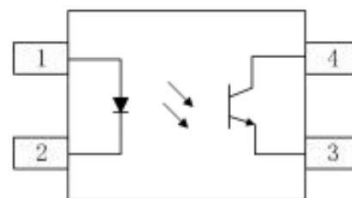
应用 Applications

- 开关电源, 智能电表
Switching power supply, intelligent meter
- 工业控制, 测量仪器
Industrial control, measuring instruments
- 办公设备, 比如复印机
Office equipment such as copiers
- 家用电器, 比如空调、风扇、热水器等
Household appliances: such as air conditioners, fans, water heaters, etc.

封装和原理图 Package and Schematic Diagram




LSOP4



Pin Configuration

1. Anode
2. Cathode
3. Emitter
4. Collector

印字信息 **Marking Information**

印字中 “” 为奥特品牌LOGO

“” denotes LOGO

印字中的 “X” 代表产品分档：0、1、2、3....

“X” denotes the classification: 0、1、2、3....

印字中 “Y” 代表年份；A(2018),B(2019),C(2020)..... “Y” denotes YEAR: A(2018), B(2019), C(2020).....

印字中 “WW” 代表周号

“WW” denotes Week' s number

印字中 “N” 代表星期几

“N” denotes the day of the week

印字中的 “H” 代表无卤

“H” denotes Halogen-free



绝缘和安规信息 Insulation and Safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	> 8.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	> 8.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	> 0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	1500	V_{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	7000	V_{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	Viso	>5000	Vrms	For 1 min

极限参数 Absolute Maximum Ratings (Ta=25°C)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I_F	50	mA
	反向电压 Reverse Voltage	V_R	6	V
	功耗 Power Dissipation	P_D	70	mW
接收端 output	集电极功耗 Collector Power Dissipation	P_C	150	mW
	集电极电流 Collector Current	I_C	50	mA
	集电极-发射极电压 Collector-Emitter Voltage	V_{CEO}	80	V
	发射极-集电极电压 Emitter-Collector Voltage	V_{ECO}	6	V
总功耗 Total Power Dissipation	P_{tot}	250	mW	
隔离电压 Isolation Voltage	V_{iso}	5000	Vrms	
工作温度 Operating Temperature	T_{opr}	-55~+110	°C	
存储温度 Storage Temperature	T_{stg}	-55~+125	°C	
焊接温度 Soldering Temperature	T_{sol}	260	°C	

产品特性参数 Electro-optical Characteristics (Ta=25°C)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
发射端 Input	正向电压 Forward Voltage	V _F	I _F =20mA	-	1.2	1.4	V
	反向电流 Reverse Current	I _R	V _R =4V	-	-	10	μA
	输入电容 Terminal Capacitance	C _t	V=0, f=1MHz	-	30	250	pF
接收端 Output	集电极暗电流 Collector Dark Current	I _{CEO}	V _{CE} =20V, I _F =0mA	-	-	100	nA
	集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =0.1mA, I _F =0mA	80	-	-	V
传输特性 Transfer Characteristics	发射极-集电极击穿电压 Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E =10μA, I _F =0mA	6	-	-	V
	集电极-发射极饱和压降 Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _E =10mA, I _C =1mA	-	-	0.3	V
	响应时间(ON) Response Time (ON)	T _{on}	V _{CE} =5V, I _C =5mA R _L =100Ω	-	4	-	μs
	响应时间(OFF) Response Time (OFF)	T _{off}	V _{CE} =5V, I _C =5mA R _L =100Ω	-	3	-	μs
	上升时间 Rise Time	T _r	V _{CE} =5V, I _C =5mA R _L =100Ω	-	2	18	μs
	下降时间 Fall Time	T _f	V _{CE} =5V, I _C =5mA R _L =100Ω	-	3	18	μs
	截止频率 Cut-off Frequency	F _c	V _{CE} =5V, I _C =2mA R _L =100Ω, -3dB	-	80	-	kHz

 注*：电流传输比=I_C/I_F x 100%。

 Note*: CTR=I_C/I_F x 100%。

电流传输比分档表 CTR Classification Table (Ta=25°C)

参数 Parameter	符号 Symbol	条件 Condition	最小值 Min.	标准值 Typ.	最大值 Max.	单位 Unit	
传输特性 Transfer Characteristics	电流传输比 CTR*	AT1010	I _F =5mA, V _{CE} =5V	50	-	600	%
		AT1017	I _F =5mA, V _{CE} =5V	80	-	160	%
		AT1018	I _F =5mA, V _{CE} =5V	130	-	260	%
		AT1019	I _F =5mA, V _{CE} =5V	200	-	400	%
		AT1012	I _F =10mA, V _{CE} =5V	63	-	125	%
		AT1013	I _F =10mA, V _{CE} =5V	100	-	200	%
		AT1014	I _F =10mA, V _{CE} =5V	160	-	320	%
		AT1012	I _F =1mA, V _{CE} =5V	22	-	-	%
		AT1013	I _F =1mA, V _{CE} =5V	34	-	-	%
		AT1014	I _F =1mA, V _{CE} =5V	56	-	-	%

典型光电特性曲线 **Typical Electro-Optical Characteristics Curves**

Fig.1 Forward Current vs Forward Voltage

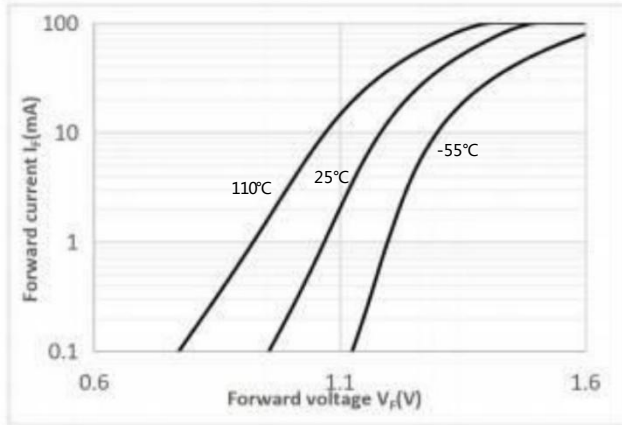


Fig.2 Collector Dark Current vs Ambient Temperature

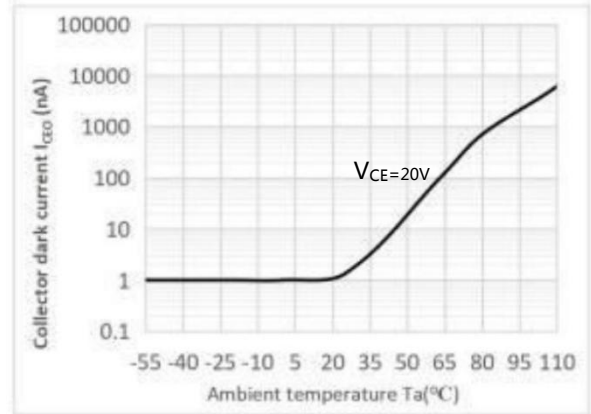


Fig.3 Collector Current vs. Collector-emitter Voltage

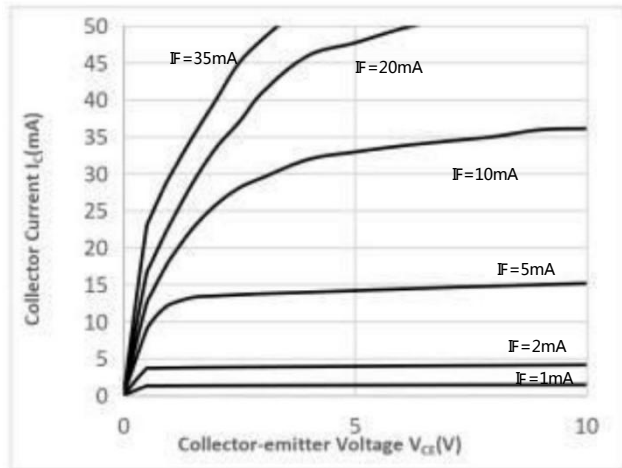


Fig.4 Relative Collector Current vs Forward Current

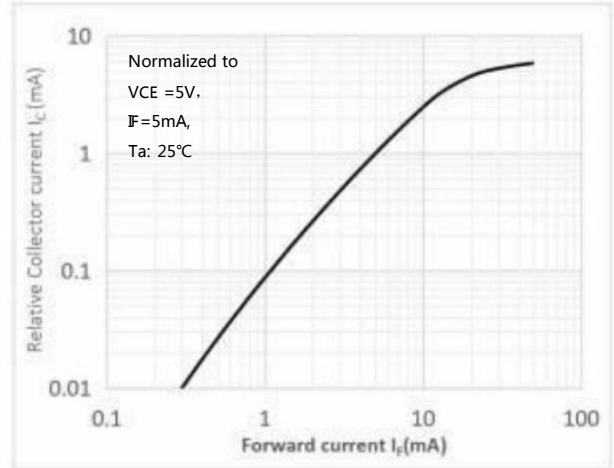


Fig.5 Relative Current Transfer Ratio vs. Forward Current

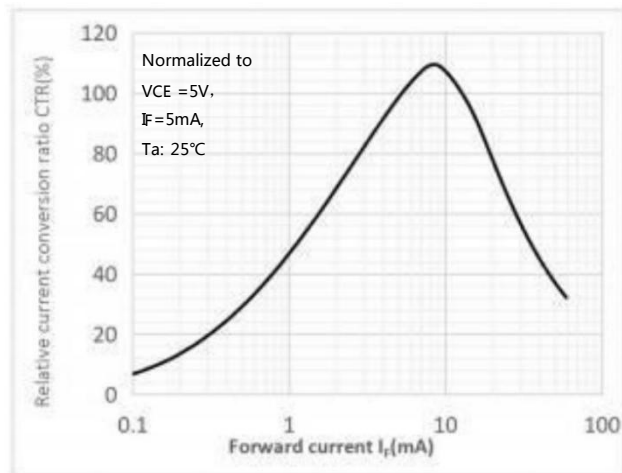


Fig.6 Relative Current transfer ratio vs Ambient temperature

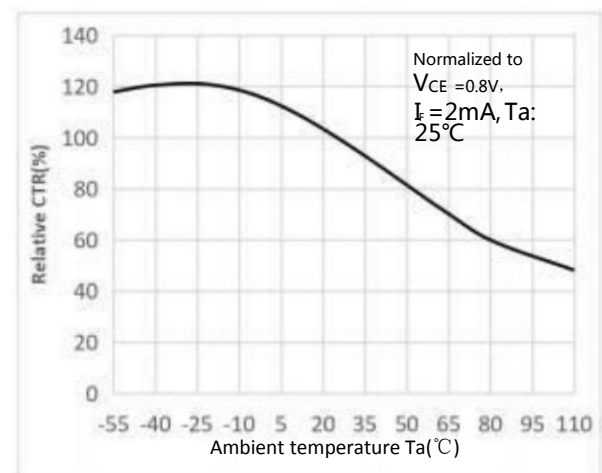


Fig.7 Relative Current transfer ratio vs Ambient temperature

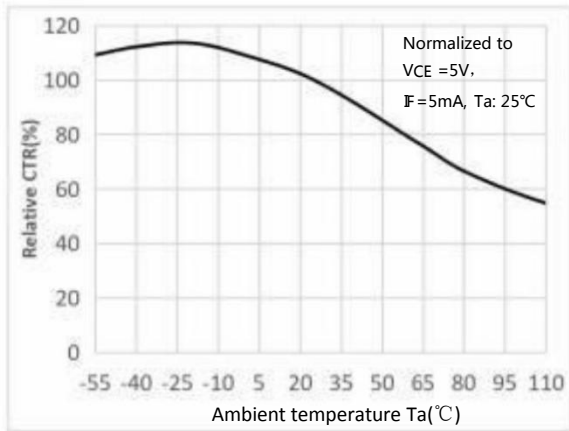


Fig.8 Collector-emitter Saturation Voltage vs. Ambient temperature

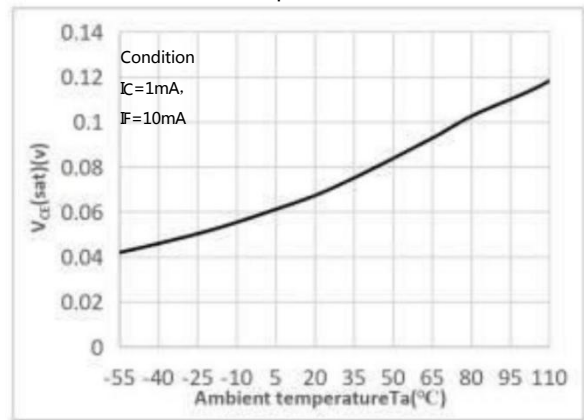


Fig.9 Turn on/Turn off vs. Collector Current

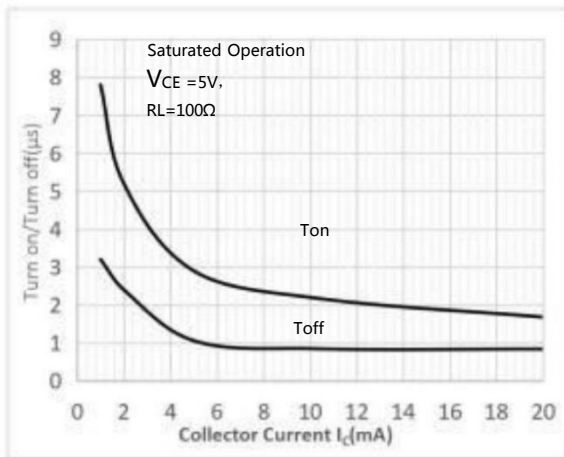


Fig.10 Turn on/Turn off vs Forward current

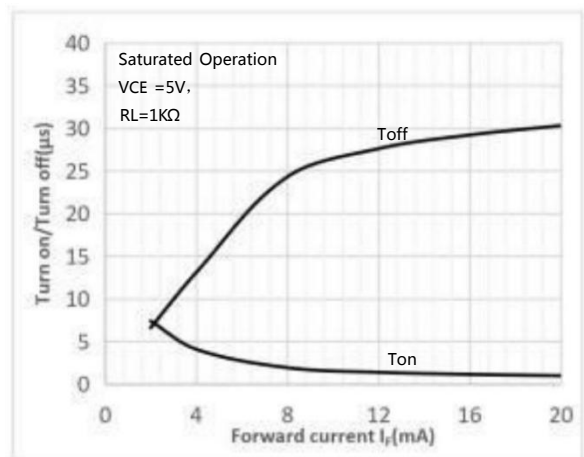
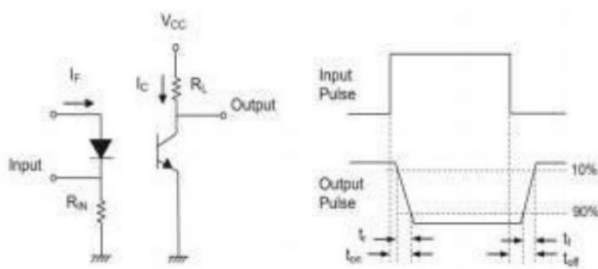
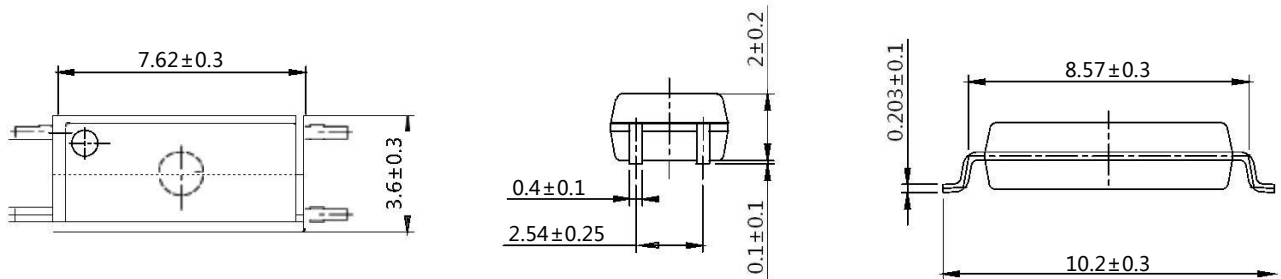


Fig.11 Switching Time Test Circuit & Waveforms



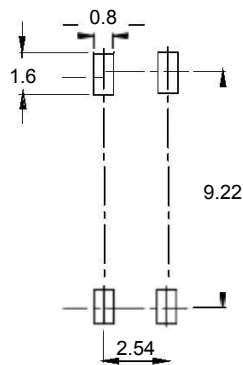
外形尺寸 **Outline Dimensions**

LSOP4



单位 Unit: mm

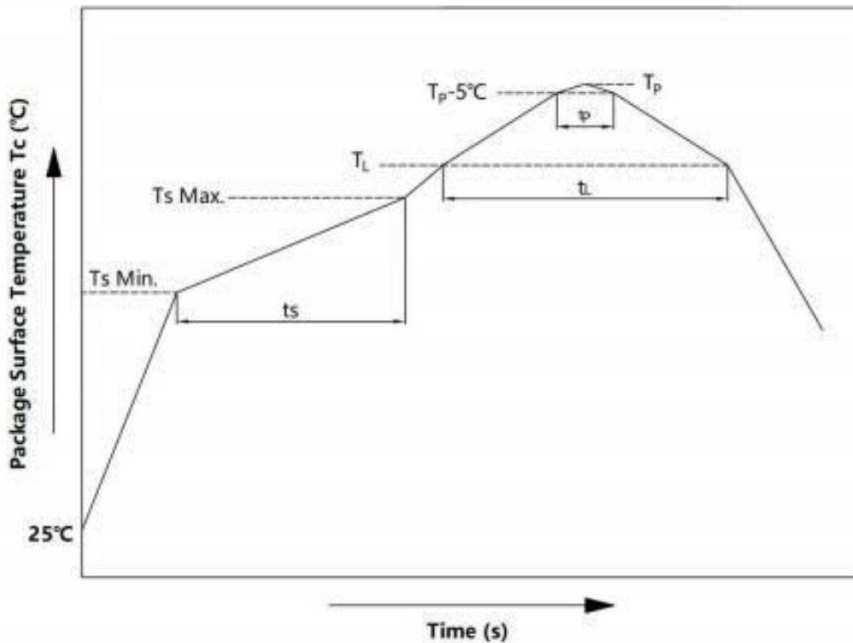
建议焊盘布局 **Recommended Pad Layout**



单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

回流焊温度曲线图 Solder Reflow Profile


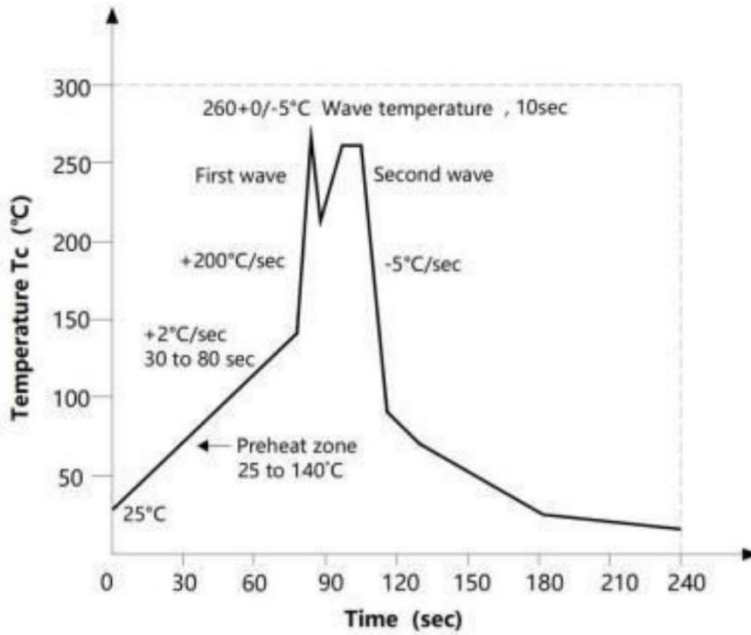
项目 Item	符号 Symbol	最小值 Min.	最大值 Max.	单位 Unit
预热温度 Preheat Temperature	Ts	150	200	°C
预热时间 Preheat Time	ts	60	120	s
升温速率 Ramp-Up Rate (TL to TP)	-	-	3	°C/s
液相线温度 Liquidus Temperature	TL	217		°C
时间高于 TL Time Above TL	tL	60	150	s
峰值温度 Peak Temperature	TP	-	260	°C
Tc 在(Tp-5)和 TP 之间的时间 Time During Which Tc Is Between (TP-5) and TP	tp	-	30	s
降温速率 Ramp-down Rate(Tp to TL)	-	-	6	°C/s

注 Note:

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 **Wave Soldering Profile**



手工烙铁焊接 **Soldering with hand soldering iron**

- A. 手工烙铁焊仅用于产品返修或样品测试;
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求: 温度 360°C ± 5°C, 时间 ≤ 3s。
Hand soldering iron requirements: Temperature: 360°C ± 5°C, within 3s.

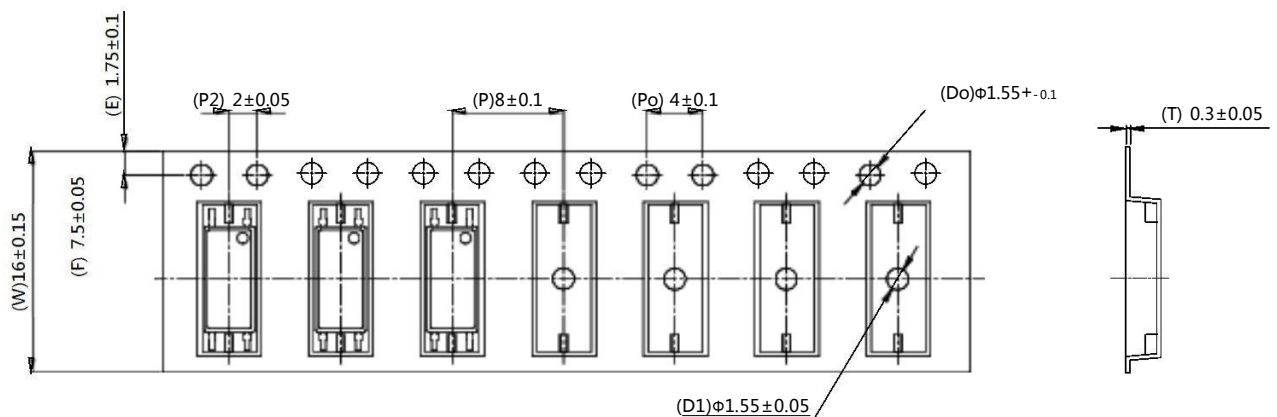
包装 Packing

■ 汇总表 Summary table

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
LSOP4	卷盘 ($\phi 330\text{mm}$ 蓝盘)	3000 只/盘	2 盘/盒	10 盒/箱	450*390*0.1mm	34*6*34cm	38*36*36.5cm	首端各空 50 个 空格, 末端空 100
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
LSOP4	Reel ($\phi 330\text{mm}$ Blue)	3000 pcs /reel	2 reels /box	10 boxes /ctn	450*390*0.1mm	34*6*34cm	38*36*36.5cm	Leave 50 Spaces at the beginning and 100 Spaces at the end

■ 编带包装 Tape & Reel

- 1) 每卷数量: 3000 只。
Qty/reel: 3000 pcs.
- 2) 每箱数量: 60000 只。
Qty/ctn: 60000 pcs.
- 3) 内包装: 每盒 2 盘。
Inner packing: 2 reels/box.
- 4) 示意图 Schematic:



单位/unit: mm

注意 **Attention**

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